

#### **Description**

The WPE0502S2 is an uni-directional TVS diode array, utilizing leading monolithic silicon technology to provide fast response time and low ESD clamping voltage, making this device an ideal solution for protecting sensitive semiconductor components from damage. The WPE0502S2 complies with the IEC 61000-4-2 (ESD) standard with ±25kV air and ±20kV contact discharge. It is assembled into a lead-free SOT-23 package. It is designed to protect components which are connected to data and transmission lines from voltage surges .

#### **Features**

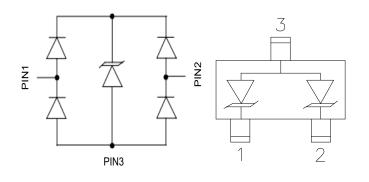
- 80W Peak pulse power (8/20us)
- Protects one differential line & two common lines
- Ultra low leakage: nA level
- Ultra low clamping voltage
- Complies with following standards:
  - IEC 61000-4-2 (ESD) immunity test

Air discharge: ±25kV

Contact discharge: ±20kV

- IEC61000-4-5 (Lightning) 5A (8/20)
- RoHS Compliant

### **Dimensions and Pin Configuration**



Circuit Diagram

Pin Schematic

### **Mechanical Characteristics**

■ Package: SOT-23

Lead Finish: Matte Tin

Case Material: "Green" Molding Compound.

■ Moisture Sensitivity: Level 3 per J-STD-020

Terminal Connections: See Diagram Below

Marking Information: See Below

### **Applications**

- Cellular Handsets and Accessories
- Personal Digital Assistants
- Notebooks and Handhelds
- Portable Instrumentation
- Set Top Box
- Industrial Controls
- Server and Desktop PC

### **Marking information**



Details marking code reference customer approval list

# **Ordering Information**

Part Number	Packaging	Reel Size	
WPE0502S2	3000/Tape & Reel	7 inch	



# Absolute Maximum Ratings (T<sub>A</sub>=25°C unless otherwise specified)

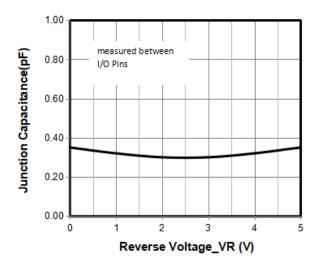
Parameter	Symbol	Value	Unit
Peak Pulse Power (8/20µs)	Ppk	80	W
Peak Pulse Current (8/20µs)	lpp	5	А
ESD per IEC 61000-4-2 (Air)		±25	
ESD per IEC 61000-4-2 (Contact)	VESD	±20	kV
Operating Temperature Range	TJ	-55 to +125	°C
Storage Temperature Range	Tstg	-55 to +150	°C

# Electrical Characteristics (T<sub>A</sub>=25°C unless otherwise specified)

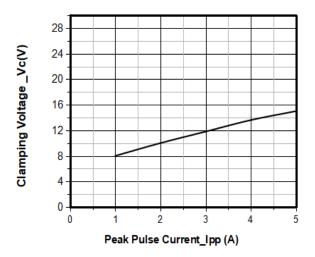
Parameter	Symbol	Min	Тур	Max	Unit	Test Condition
Reverse Working Voltage	VRWM			5	V	
Breakdown Voltage	VBR	6			V	IT = 1mA
Reverse Leakage Current	IR		0.01	0.5	uA	VRWM = 5.5V
Clamping Voltage	VC			9	V	IPP = 1A (8 x 20uS pulse)
Clamping Voltage	VC			16	V	IPP = 5A (8 x 20uS pulse)
Junction Capacitance	CJ		0.3	0.4	pF	VR = 0V, f = 1MHz, between pin 1 and pin 2
Junction Capacitance	CJ			0.8	pF	VR = 0V, f = 1MHz, pin 1 or pin 2 to pin 3

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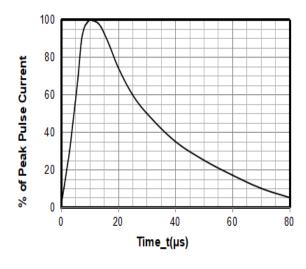
### Typical Performance Characteristics (T<sub>A</sub>=25°C unless otherwise Specified)



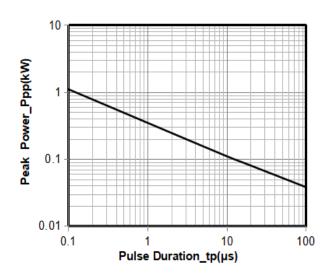
Junction Capacitance vs. Reverse Voltage



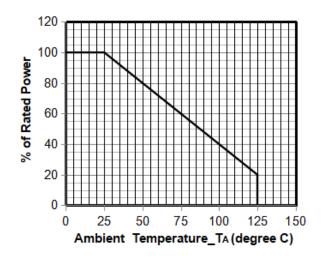
Clamping Voltage vs. Peak Pulse Current



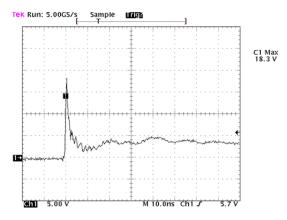
8 X 20µs Pulse Waveform



Peak Pulse Power vs. Pulse Time



**Power Derating Curve** 



Note: Data is taken with a 10x attenuator

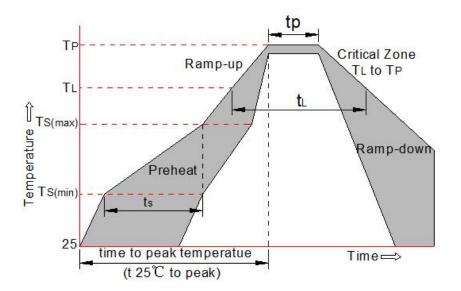
ESD Clamping Voltage

8 kV Contact per IEC61000-4-2

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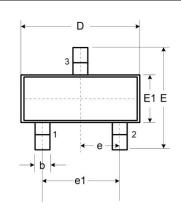
Reflow Condition		Pb-Free assembly (see FIG.2)	
	-Temperature Min (T <sub>s(min)</sub> )	+150℃	
Pre Heat	-Temperature Max(T <sub>s(max)</sub> )	+200℃	
	-Time (Min to Max) (ts)	60-180 secs.	
Average ramp	up rate (Liquid us Temp (T <sub>L</sub> ) to peak)	3℃/sec. Max	
T <sub>s(max)</sub> to T <sub>L</sub> - R	amp-up Rate	3℃/sec. Max	
Reflow	-Temperature(T <sub>L</sub> ) (Liquid us)	+217℃	
Reliow	-Temperature(t <sub>L</sub> )	60-150 secs.	
Peak Temp (Tp	5)	+260(+0/-5)°C	
Time within 5°	C of actual Peak Temp (t <sub>p</sub> )	30 secs. Max	
Ramp-down R	ate	6°C/sec. Max	
Time 25°C to F	Peak Temp (T <sub>P</sub> )	8 min. Max	
Do not exceed		+260℃	

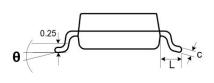


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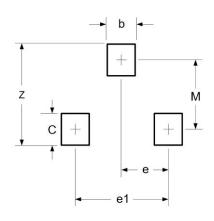
## Package mechanical data





DIMENSIONS					
SYMBOL	MILLIN	METER	INCHES		
OTWIDOL	MIN	MAX	MIN	MAX	
Α	0.90	1.15	0.035	0.045	
A1	0.00	0.10	0.000	0.004	
A2	0.60	0.70	0.0236	0.0275	
b	0.30	0.50	0.012	0.020	
С	0.08	0.15	0.003	0.006	
D	2.80	3.00	0.110	0.118	
E	2.25	2.55	0.089	0.100	
E1	1.20	1.40	0.047	0.055	
е	0.95 BSC		0.037	74 BSC	
e1	1.80	2.00	0.071	0.079	
Ĺ	0.30	0.50	0.012	0.020	
θ	0	8°	0	8.	





DIMENSIONS			
DIM INCHES		MILLIMETERS	
М	0.0795	2.02	
С	0.0315	0.80	
Z	0.111	2.82	
е	0.037 BSC	0.95 BSC	
e1	0.075 BSC	1.9 BSC	
b 0.0315		0.80	

## **Contact Information**

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